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## Vishay Semiconductors

## AAP Gen 7 (TO-240AA) Power Modules Standard Diodes, 80 A



AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	80 A				
Туре	Modules - Diode, High Voltage				
Package	AAP Gen 7 (TO-240AA)				
Circuit configuration	Two diodes doubler circuit, two diodes common cathode, two diodes common anode, single diode				

### **MECHANICAL DESCRIPTION**

The AAP Gen 7 (TO-240AA), new generation of AAP module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- High voltage
- Industrial standard package
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
1		80	A		
I <sub>F(AV)</sub>	T <sub>C</sub>	110	С°		
I <sub>F(RMS)</sub>		126			
I <sub>FSM</sub>	50 Hz	1500	А		
	60 Hz	1570			
l <sup>2</sup> t	50 Hz	11.25	kA <sup>2</sup> s		
1-1	60 Hz	10.26	KA-S		
l²√t		112.5	kA²√s		
V <sub>RRM</sub>	Range	400 to 1600	V		
T <sub>Stg</sub> , T <sub>J</sub>		-40 to +150	°C		

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1



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### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER VOLTAGE CODE		V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 150 °C mA		
	04	400	500			
	06	600	700	]		
	08	800	900			
VS-VSK.71	10	1000	1100	10		
	12	1200	1300			
	14	1400	1500			
	16	1600	1700	]		

FORWARD CONDUCTION							
PARAMETER	SYMBOL		TEST CON	VALUES	UNITS		
Maximum average forward current at case temperature	I <sub>F(AV)</sub>	180° condu	ction, half sine	80 110	A °C		
Maximum RMS forward current	I <sub>F(RMS)</sub>			126	-		
		t = 10 ms	No voltage		1500		
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		1570	А	
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		1260		
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1320		
	l <sup>2</sup> t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	11.25	kA <sup>2</sup> s	
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	reapplied		10.26		
Maximum -t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		7.95		
		t = 8.3 ms	reapplied		7.23		
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	112.5	kA²√s		
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	(I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum	0.73	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)})$	)), T <sub>J</sub> = T <sub>J</sub> maxir	num	0.83	v	
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	3.22	mΩ		
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			2.89	11152	
Maximum forward voltage drop	V <sub>FM</sub>	$I_{FM} = \pi \times I_{F(I)}$	<sub>AV)</sub> , T <sub>J</sub> = 25 °C, †	t <sub>p</sub> = 400 μs square wave	1.6	V	

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak reverse leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C	10	mA		
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V		

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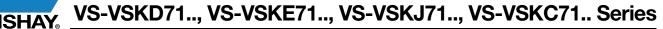
THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Junction and storage temp	erature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C	
Maximum internal thermal r junction to case per leg	resistance,	R <sub>thJC</sub>	DC operation	0.28		
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	°C/W	
	to heatsink		A mounting compound is recommended and the	4		
Mounting torque ± 10 %	busbar		torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm	
Approximate weight				75	g	
Approximate weight				2.7	oz.	
Case style			JEDEC®	AAP Gen 7	(TO-240AA)	

DEVICES	S	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS
DEVICES	180°	120°	90°	60°	30°	180°	120°	<b>90</b> °	60°	<b>30</b> °	UNITS
VSK.71	0.075	0.088	0.113	0.155	0.228	0.06	0.094	0.12	0.158	0.23	°C/W

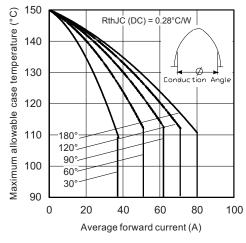
#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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Fig. 1 - Current Ratings Characteristics

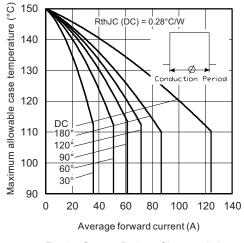


Fig. 2 - Current Ratings Characteristics

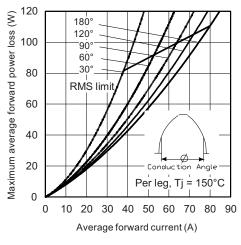


Fig. 3 - Forward Power Loss Characteristics

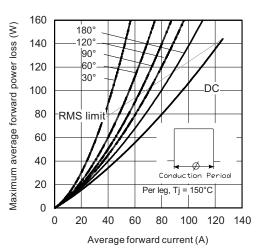


Fig. 4 - Foward Power Loss Characteristics

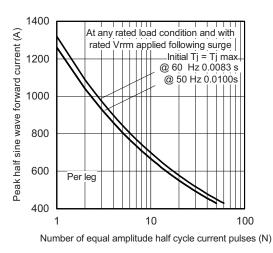
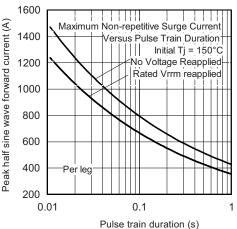


Fig. 5 - Maximum Non-Repetitive Surge Current



Pulse train duration (s)

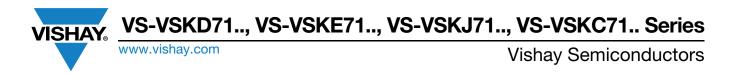
Fig. 6 - Maximum Non-Repetitive Surge Current

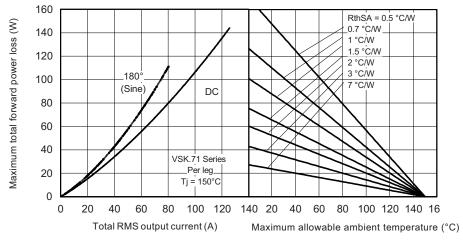
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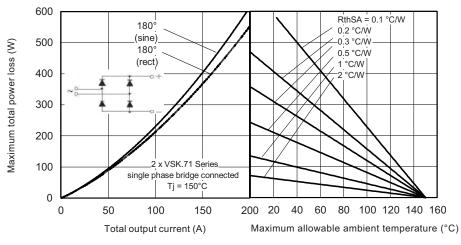
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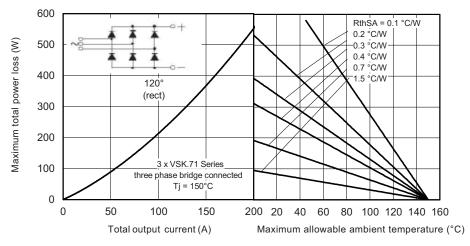






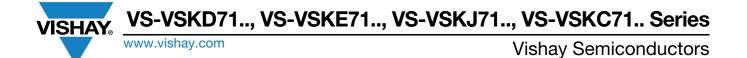








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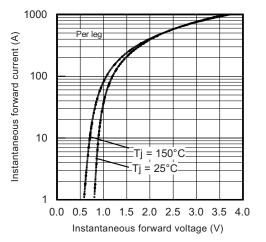


Fig. 10 - Forward Voltage Characteristics

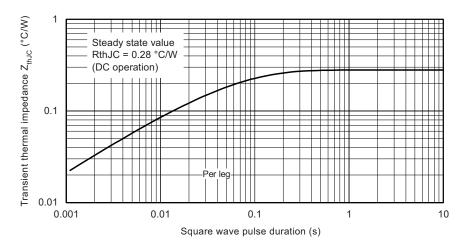
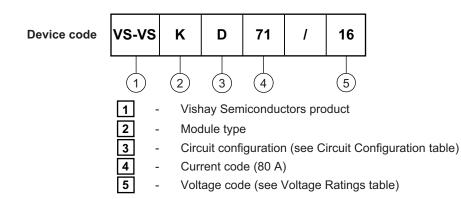


Fig. 11 - Thermal Impedance ZthJC Characteristics

### **ORDERING INFORMATION TABLE**



#### Note

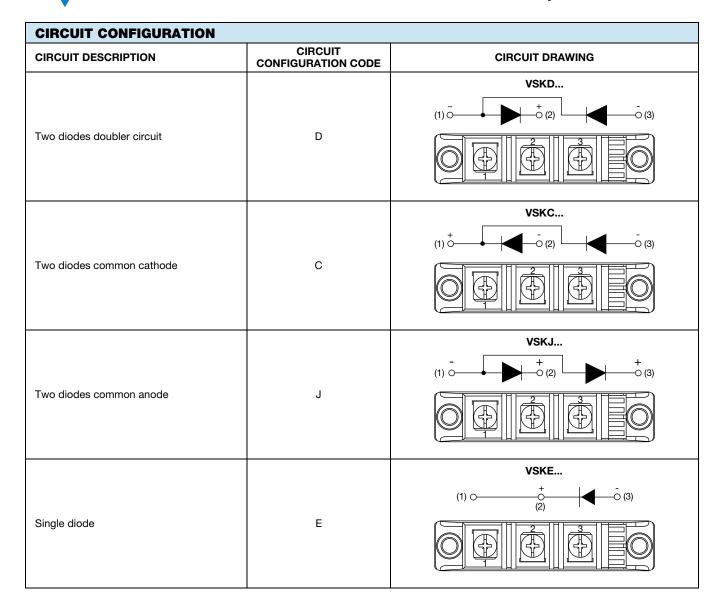
To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

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	LINKS TO RELATED DOCUMENTS
Dimensions	www.vishay.com/doc?95369

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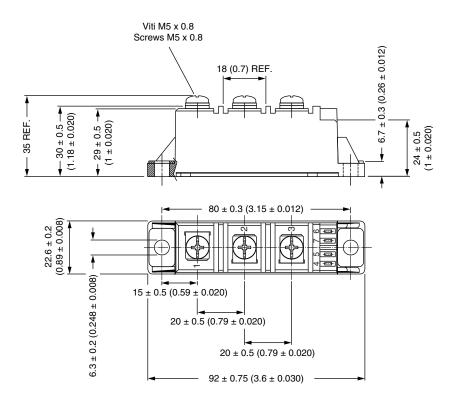
7



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**DIMENSIONS** in millimeters (inches)







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